

MM74C901, MM74C902

Hex Inverting TTL Buffer, Hex Non-Inverting TTL Buffer

The MM74C901 and MM74C902 hex buffers employ complementary MOS to achieve wide supply operating range, low power consumption, and high noise immunity. These buffers provide direct interface from PMOS into CMOS or TTL and direct interface from CMOS to TTL or CMOS operating at a reduced V_{CC} supply.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing. FAIRCHILD

SEMICONDUCTOR

MM74C901 • MM74C902 Hex Inverting TTL Buffer • Hex Non-Inverting TTL Buffer

General Description

The MM74C901 and MM74C902 hex buffers employ complementary MOS to achieve wide supply operating range, low power consumption, and high noise immunity. These buffers provide direct interface from PMOS into CMOS or TTL and direct interface from CMOS to TTL or CMOS operating at a reduced V_{CC} supply.

Features

- Wide supply voltage range: 3.0V to 15V
- Guaranteed noise margin: 1.0V
- High noise immunity: 0.45 V_{CC} (typ.)
- TTL compatibility: Fan out of 2 driving standard TTL

October 1987

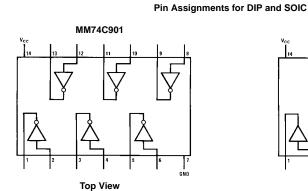
Revised January 1999

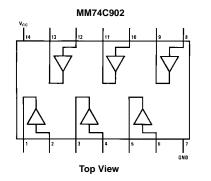
Ordering Code:

Order Number	Package Number	Package Description
MM74C901M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
MM74C901N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-011, 0.300" Wide
MM74C902M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
MM74C902N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-011, 0.300" Wide

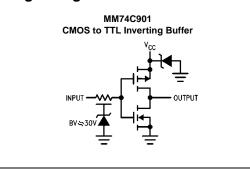
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

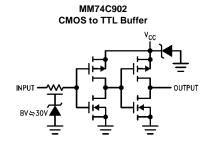
Connection Diagrams





Logic Diagrams





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MM74C901 • MM74C902 Hex Inverting TTL Buffer • Hex Non-Inverting TTL Buffer

Absolute Maximum Ratings(Note 1)

Voltage at Any Pin	–0.3V to $V_{\mbox{\scriptsize CC}}$ + 0.3V
Voltage at Any Input Pin	
MM74C901	-0.3V to +15V
MM74C902	-0.3V to +15V
Storage Temperature Range (T _S)	$-65^{\circ}C$ to $+150^{\circ}C$
Power Dissipation (P _D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating Temperature Range (T _A)	
MM74C901, MM74C902,	$-40^{\circ}C$ to $+85^{\circ}C$

Operating V _{CC} Range	3.0V to 15V
Absolute Maximum V _{CC}	18V
Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

DC Electrical Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Units
MOS TO	CMOS					
IN(1)	Logical "1" Input Voltage	V _{CC} = 5.0V	3.5			V
		$V_{CC} = 10V$	8.0			V
V IN(0)	Logical "0" Input Voltage	V _{CC} = 5.0V			1.5	V
		$V_{CC} = 10V$			2.0	V
V OUT(1)	Logical "1" Output Voltage	$V_{CC} = 5.0V, I_{O} = -10 \mu A$	4.5			V
		$V_{CC} = 10V, I_{O} = -10 \ \mu A$	9.0			V
V _{OUT(0)}	Logical "0" Output Voltage	V _{CC} = 5.0V			0.5	V
		$V_{CC} = 10V$			1.0	V
N(1)	Logical "1" Input Current	V _{CC} = 15V, V _{IN} = 15V		0.005	1.0	μA
N(0)	Logical "0" Input Current	V _{CC} = 15V, V _{IN} = 0V	-1.0	-0.005		μA
cc	Supply Current	V _{CC} = 15V		0.05	15	μA
TL TO CN	ios					
IN(1)	Logical "1" Input Voltage	V _{CC} = 4.75V	V _{CC} – 1.5			V
IN(0)	Logical "0" Input Voltage	V _{CC} = 4.75V			0.8	V
MOS TO	TTL					
IN(1)	Logical "1" Input Voltage					
.,	MM74C901	$V_{CC} = 4.75V$	4.25			V
	MM74C902	V _{CC} = 4.75V	V _{CC} – 1.5			v
IN(0)	Logical "0" Input Voltage					
(-)	MM74C901	V _{CC} = 4.75V			1.0	V
	MM74C902	V _{CC} = 4.75V			1.5	V
OUT(1)	Logical "1" Output Voltage	$V_{CC} = 4.75 V$, $I_{O} = -800 \mu A$	2.4			V
OUT(0)	Logical "0" Output Voltage					
001(0)	MM74C901	$V_{CC} = 4.75V, I_{O} = 2.6 \text{ mA}$			0.4	v
	MM74C902	$V_{CC} = 4.75 V$, $I_{O} = 3.2 mA$			0.4	v
UTPUT D	RIVE (See Family Characteristics	Data Sheet) (Short Circuit Current)				
(MM74C	901)					
SOURCE	Output Source Current	$V_{CC} = 5.0V, V_{OUT} = 0V$	-5.0			mA
	(P-Channel)	$T_A = 25^{\circ}C, V_{IN} = 0V$				
SOURCE	Output Source Current	V _{CC} = 10V, V _{OUT} = 0V	-20			mA
	(P-Channel)	$T_A = 25^{\circ}C, V_{IN} = 0V$				
SINK	Output Sink Current	$V_{CC} = 5.0V, V_{OUT} = V_{CC}$	9.0			mA
	(N-Channel)	$T_A = 25^{\circ}C, V_{IN} = V_{CC}$				
SINK	Output Sink Current	$V_{CC} = 5.0V, V_{OUT} = 0.4V$	3.8			mA
0	(N-Channel)	$T_A = 25^{\circ}C, V_{IN} = V_{CC}$				

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	Parameter	Conditions	Min	Тур	Max	Units
SOURCE	Output Source Current	$V_{CC} = 5.0V, V_{OUT} = 0V$	-5.0			mA
	(P-Channel)	$T_A = 25^{\circ}C, V_{IN} = V_{CC}$				
SOURCE	Output Source Current	$V_{CC} = 10V, V_{OUT} = 0V$	-20			mA
	(P-Channel)	$T_A = 25^{\circ}C, \ V_{IN} = V_{CC}$				
SINK	Output Sink Current	$V_{CC} = 5.0V, V_{OUT} = V_{CC}$	9.0			mA
	(N-Channel)	$T_A = 25^{\circ}C, \ V_{IN} = 0V$				
SINK	Output Sink Current	$V_{CC} = 5.0V, V_{OUT} = 0.4V$	3.8			mA
	(N-Channel)	$T_A = 25^{\circ}C, V_{IN} = 0V$				

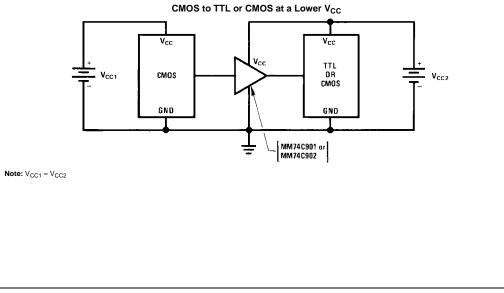
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21 5.0\ ns t _{pd0} CC = 35 opagation D $V_{CC} = 10V$ 13 20 ns to a Logical "0" C_{IN} Input Capacitance Any Input (Note 3) 14 pF Per Buffer (Note 4) C_{PD} Power Dissipation Capacity 30 pF MM74C902 57 90 Propagation Delay Time $V_{CC} = 5.0V$ ns t _{pd1} $V_{CC} = 10V$ to a Logical "1" 27 40 ns V_{CC} = 5.0V Propagation Delay Time 54 90 ns t _{pd0} $V_{CC} = 10V$ 25 40 to a Logical "0" ns Any Input (Note 3) pF Input Capacitance 5.0 C IN C _{PD} Per Buffer (Note 4) 50 Power Dissipation Capacity рF Note 2: AC Parameters are guaranteed by DC correlated testing.

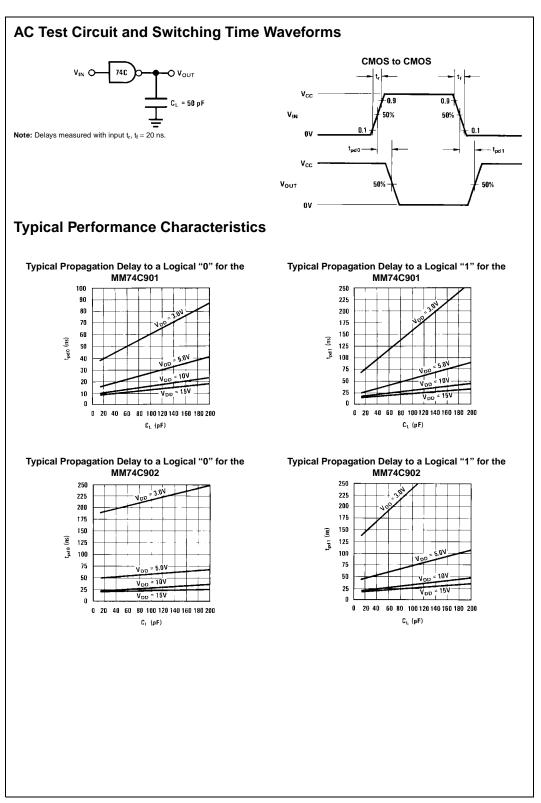
Note 3: Capacitance is guaranteed by periodic testing.

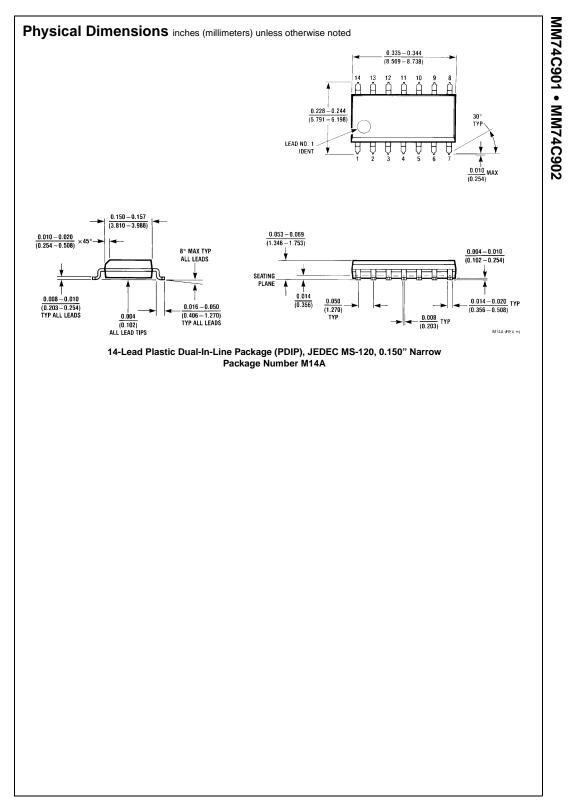
Note 4: CPD determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics application note AN-90.

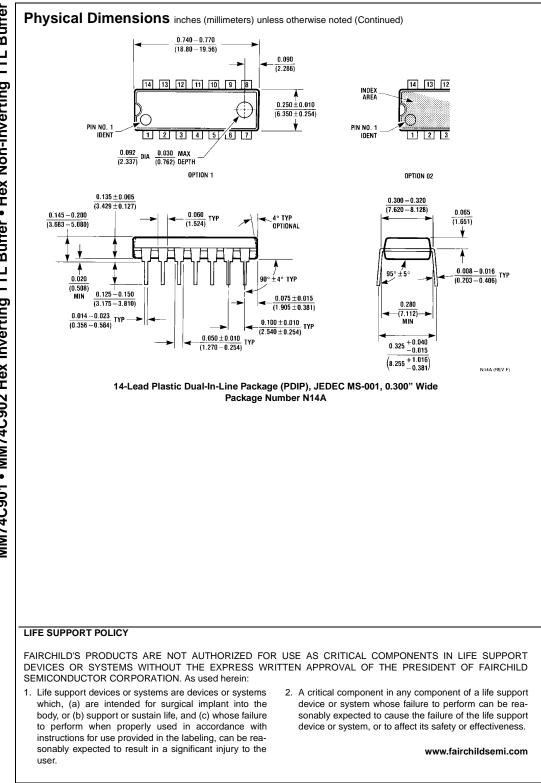
Typical Application



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